SN54HC640, SN74HC640 OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS SCLS303A – JANUARY 1996 – REVISED MAY 1997

- Inverting Logic
- High-Current 3-State Outputs Can Drive up to 15 LSTTL Loads
- Package Options Include Plastic Small-Outline (DW) and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. These devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending upon the level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated.

The SN54HC640 is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74HC640 is characterized for operation from -40° C to 85°C.

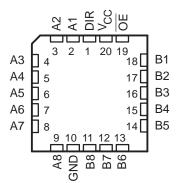
FUNCTION	TABLE
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1	NPUTS	
O	E DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Х	Isolation
-		

SN54HC640	. J OR W PACKAGE
SN74HC640	DW OR N PACKAGE
(TC	P VIEW)

	(101 11211)										
DIR [A1 [A2 [A3 [A4 [A5]	5	20 19 18 17 16 15] V _{CC}] OE] B1] B2] B3] B4								
A6 [14	B5								
A7 [8	13] B6								
A8 [9	12] B7								
GND [10	11] B8								

SN54HC640 . . . FK PACKAGE (TOP VIEW)





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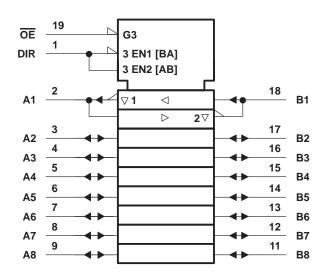
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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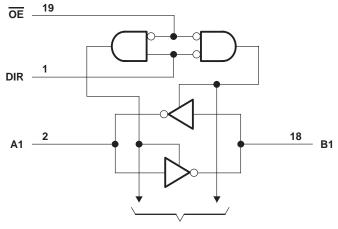
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



To Seven Other Transceivers



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absolute maximum ratings over operating free-air temperature range[†]

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input clamp current, I_{IK} (V _I < 0 or V _I > V _{CC}) (see Note 1)	
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC}) (see Note 1)	±20 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	±35 mA
Continuous current through V _{CC} or GND	±70 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package	
N package	
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

			SI	154HC64	40	SN74HC640			
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage		2	5	6	2	5	6	V
		V _{CC} = 2 V	1.5			1.5			
VIH	High-level input voltage	$V_{CC} = 4.5 V$	3.15			3.15			V
		V _{CC} = 6 V	4.2			4.2			
		V _{CC} = 2 V	0		0.5	0		0.5	
VIL	Low-level input voltage	V _{CC} = 4.5 V	0		1.35	0		1.35	V
		ACC = 6 A	0		1.8	0		1.8	
VI	Input voltage		0		VCC	0		VCC	V
VO	Output voltage		0		VCC	0		VCC	V
		V _{CC} = 2 V	0		1000	0		1000	
t _t	Input transition (rise and fall) time	V _{CC} = 4.5 V	0		500	0		500	ns
		V _{CC} = 6 V	0		400	0		400	
Тд	Operating free-air temperature	÷	-55		125	-40		85	°C

recommended operating conditions



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		N	T _A = 25°C			SN54HC640		SN74HC640		UNIT
				Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
				2 V	1.9	1.998		1.9		1.9		
			I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
∨он		$V_I = V_{IH} \text{ or } V_{IL}$		6 V	5.9	5.999		5.9		5.9		V
			I _{OH} = –6 mA	4.5 V	3.98	4.3		3.7		3.84		
			I _{OH} = -7.8 mA	6 V	5.48	5.8		5.2		5.34		
				2 V		0.002	0.1		0.1		0.1	
			I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	
VOL		$V_I = V_{IH} \text{ or } V_{IL}$		6 V		0.001	0.1		0.1		0.1	V
			I _{OL} = 6 mA	4.5 V		0.17	0.26		0.4		0.33	
			I _{OL} = 7.8 mA	6 V		0.15	0.26		0.4		0.33	
Ц	DIR or OE	$V_{I} = V_{CC} \text{ or } 0$		6 V		±0.1	±100		±1000		±1000	nA
loz	A or B	$V_{O} = V_{CC} \text{ or } 0$		6 V		±0.01	±0.5		±10		±5	μΑ
ICC		$V_{I} = V_{CC} \text{ or } 0,$	I <mark>O</mark> = 0	6 V			8		160		80	μΑ
Ci	DIR or OE			2 V to 6 V		3	10		10		10	pF

switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	ом то усс		Т	_ = 25°C	;	SN54H	IC640	SN74H	IC640	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
			2 V		29	105		160		130		
^t pd	A or B	B or A	4.5 V		10	21		32		26	ns	
			6 V		8	18		27		22		
	t _{en} OE		2 V		109	230		340		290		
t _{en}		OE	A or B	4.5 V		27	46		68		58	ns
				6 V		20	39		58		49	
			2 V		40	150		225		190		
^t dis	ŌĒ	A or B	4.5 V		18	30		45		38	ns	
			6 V		16	26		38		32		
			2 V		20	60		90		75		
tt		A or B	4.5 V		8	12		18		15	ns	
			6 V		6	10		15		13		



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switching characteristics over recommended operating free-air temperature range, $C_L = 150 \text{ pF}$ (unless otherwise noted) (see Figure 1)

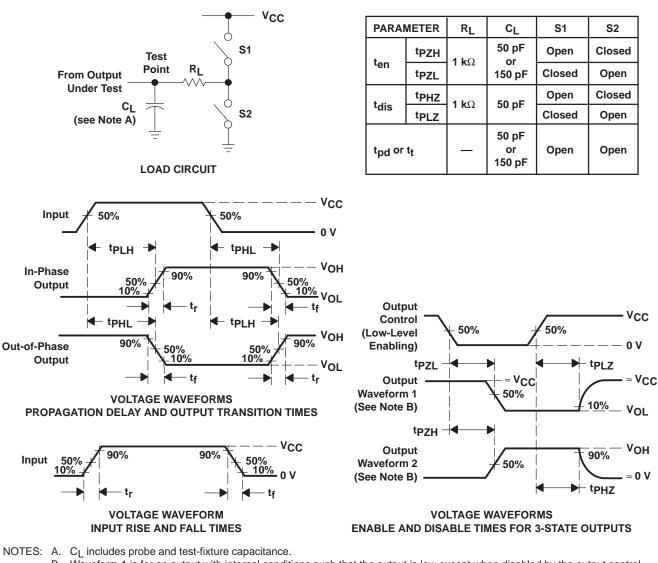
PARAMETER	FROM TO		Vee	Τį	ς = 25°C	;	SN54H	IC640	SN74H	C640	UNIT	
FARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
			2 V		44	190		290		235		
^t pd	A or B	B or A	4.5 V		14	38		58		47	ns	
			6 V		11	33		49		41		
			2 V		124	315		470		395		
t _{en}	OE	A or B	4.5 V		31	63		94		79	ns	
					6 V		23	54		80		68
			2 V		45	210		315		265		
tt		A or B	4.5 V		17	42		63		53	ns	
			6 V		13	36		53		45		

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per transceiver	No load	40	pF

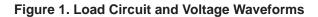


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PARAMETER MEASUREMENT INFORMATION

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
 Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. Bhase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by apparenters begins the following.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns, t_f = 6 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. tPLH and tPHL are the same as tpd.





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